NSN 5961-01-462-9959

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-462-9959

Inclosure Material:

Plastic

Overall Length:

2.9 millimeters

Overall Height:

1.4 millimeters

Overall Width:

2.8 millimeters

End Application:

6625-01-425-2551

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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